M-274

Index-Guided High Power AlGaAs Laser Diode

Description

The SLD231VL is a high-power, index-guided AlGaAs laser diode.

Features

- Low current consumption
- · Small astigmatism
- Small package (φ5.6mm)



Pickup for optical discs

Structure

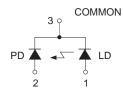
- AlGaAs quantum well structured laser diode
- PIN photodiode for optical power output monitor

Recommended Operating Optical Power Output 35mW

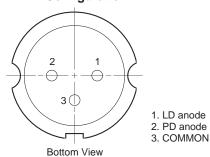
Absolute Maximum Ratings (Tc = 25°C)

 Optical power output 	Po		40	mW
Reverse voltage	VR	LD	2	V
		PD	15	V
 Operating temperature 	Topr		-10 to +60	°C
Storage temperature	Tstg		-40 to +85	°C

Connection Diagram



Pin Configuration



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Optical and Electrical Characteristics (Tc = 25°C)

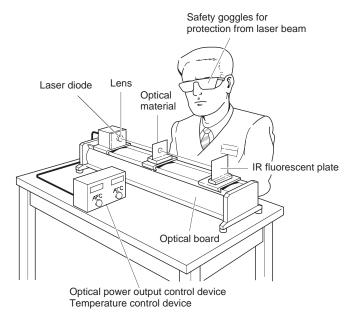
Tc: Case temperature

	Item	Symbol	Conditions	Min.	Тур.	Max.	Unit
Threshold cu	urrent	Ith		10	20	40	mA
Operating cu	ırrent	lop	Po = 35mW	35	55	70	mA
Operating vo	oltage	Vop	Po = 35mW	_	2.0	2.5	V
Wavelength		λ	Po = 35mW	780	790	800	nm
Radiation	Perpendicular	θΤ	Po = 35mW	20	24	28	degree
angle	Parallel	θ//	- FO = 33111V	7	9	12	degree
	Position	ΔΧ, ΔΥ, ΔΖ	Po = 35mW	_	_	±80	μm
Positional accuracy Angle	Anglo	Δφ⊥		_	_	±3	degree
	Aligie	Δφ//		_	_	±3	degree
Differential e	fficiency	ησ	Po = 35mW	0.7	1.0	1.3	mW/mA
Astigmatism		As	Po = 35mW	_	_	6	μm
Monitor curre	ent	lm	Po = 35mW, Vr = 5V	_	0.10	_	mA

Handling Precautions

(1) Eye protection against laser beams

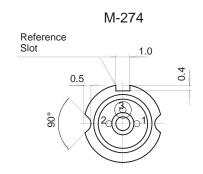
The optical output of laser diodes ranges from several mW to 4W. However the optical power density of the laser beam at the diode chip reaches 1MW/cm². Unlike gas lasers, since laser diode beams are divergent, uncollimated laser diode beams are fairly safe at a laser diode. For observing laser beams, ALWAYS use safety goggles that block infrared rays. Usage of IR scopes, IR cameras and fluorescent plates is also recommended for monitoring laser beams safely.

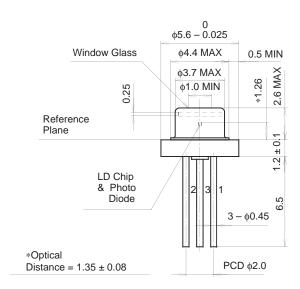


(2) Prevention of surge current and electrostatic discharge

Laser diode is most sensitive to electrostatic discharge among semiconductors. When a large current is passed through the laser diode even for an extremely short time (in the order of nanosecond), the strong light emitted from the laser diode promotes deterioration and then laser diodes are destroyed. Therefore, note that the surge current should not flow the laser diode driving circuit from switches and others. Also, if the laser diode is handled carelessly, it may be destructed instantly because electrostatic discharge is easily applied by a human body. Be great careful about excess current and electrostatic discharge.

Package Outline Unit: mm





SONY CODE	M-274
EIAJ CODE	
JEDEC CODE	

PACKAGE WEIGHT	0.3g
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